January 30, 2008



# LM185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode

## **General Description**

**Connection Diagrams** 

The LM185-2.5/LM285-2.5/LM385-2.5 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 20  $\mu$ A to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM-185-2.5 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

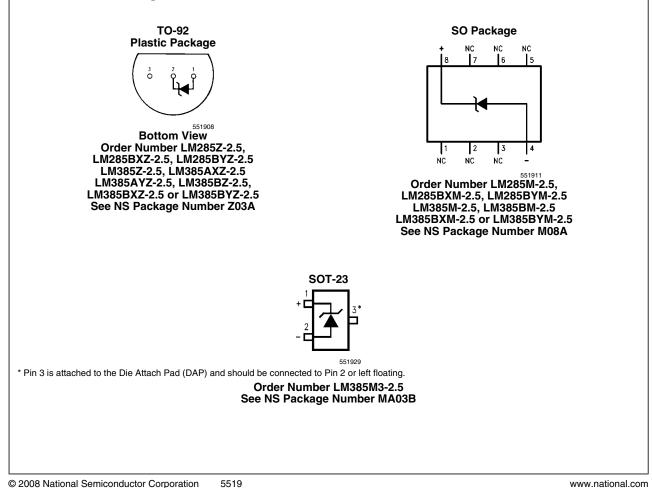
Careful design of the LM185-2.5 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

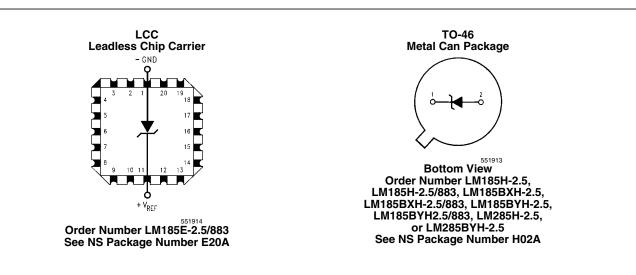
The extremely low power drain of the LM185-2.5 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part. For applications requiring 1.2V see LM185-1.2.

The LM185-2.5 is rated for operation over a  $-55^{\circ}$ C to  $125^{\circ}$ C temperature range while the LM285-2.5 is rated  $-40^{\circ}$ C to  $85^{\circ}$ C and the LM385-2.5 0°C to  $70^{\circ}$ C. The LM185-2.5/LM285-2.5 are available in a hermetic TO-46 package and the LM285-2.5/LM385-2.5 are also available in a low-cost TO-92 molded package, as well as S.O. and SOT-23. The LM185-2.5 is also available in a hermetic leadless chip carrier package.

#### **Features**

- ±20 mV (±0.8%) max. initial tolerance (A grade)
- Operating current of 20 µA to 20 mA
- 0.6Ω dynamic impedance (A grade)
- Low temperature coefficient
- Low voltage reference—2.5V
- 1.2V device and adjustable device also available— LM185-1.2 series and LM185 series, respectively





# LM185-2.5/LM285-2.5/LM385-2.5

2kV

260°C

300°C

215°C

220°C

-55°C to + 150°C

## Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current	30 mA
Forward Current	10 mA
Operating Temperature Range (Note 3)	
LM185-2.5	–55°C to + 125°C
LM285-2.5	-40°C to + 85°C
LM385-2.5	0°C to 70°C

## E

LM385-2.5	0°C to 70°C	mount device	es.		
Electrical Charae	cteristics				
	Conditions		LM385A-2.5 LM385AX-2.5 LM385AY-2.5		Units
Parameter		Тур	Tested Limit (Note 5)	Design Limit (Note 6)	(Limits)
Reverse Breakdown	I <sub>R</sub> = 100 μA	2.500	2.480		V(Min)
Voltage			2.520		V(Max)
		2.500		2.470	V(Min)
				2.530	V(Max)
Minimum Operating Current		12	18	20	μA (Max)
Reverse Breakdown	I <sub>MIN</sub> ≤ I <sub>R</sub> ≤ 1mA		1	1.5	mV
Voltage Change with					(Max)
Current	1 mA ≤ I <sub>R</sub> ≤ 20 mA		10	20	mV
					(Max)
Reverse Dynamic	I <sub>R</sub> = 100 μA,	0.2		0.6	Ω
Impedance	f = 20 Hz			1.5	
Wideband Noise (rms)	I <sub>R</sub> = 100 μA	120			μV
	10 Hz ≤ f ≤ 10 kHz				
Long Term Stability	I <sub>R</sub> = 100 μA,				
	T = 1000 Hr,	20			ppm
	$T_A = 25^{\circ}C \pm 0.1^{\circ}C$				
Average Temperature	I <sub>MIN</sub> ≤ I <sub>R</sub> ≤ 20 mA				
Coefficient (Note 7)	X Suffix		30		ppm/°C
	Y Suffix		50		(Max)
	All Others			150	

ESD Susceptibility (Note 9)

TO-92 Package (10 sec.)

TO-46 Package (10 sec.)

SO and SOT Package Vapor Phase (60 sec.)

Infrared (15 sec.)

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface

Storage Temperature

Soldering Information

3

Electrical Characteristics									
Parameter	Conditions	Тур	LM185-2.5 LM185BX-2.5 LM185BY-2.5 LM285-2.5 LM285BX-2.5 LM285BY-2.5		LM385B-2.5 LM385BX-2.5 LM385BY-2.5		LM385-2.5		Units (Limit)
			Tested Limit (Notes 5, 8)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	
Reverse Breakdown	T <sub>A</sub> = 25°C,	2.5	2.462		2.462		2.425		V(Min)
Voltage	20 µA ≤ I <sub>R</sub> ≤ 20 mA		2.538		2.538		2.575		V(Max)
Minimum Operating		13	20	30	20	30	20	30	μA
Current	LM385M3-2.5						15	20	(Max)
Reverse Breakdown Voltage	20 µA ≤ I <sub>R</sub> ≤ 1 mA		1	1.5	2.0	2.5	2.0	2.5	mV (Max)
Change with Current	1 mA ≤ I <sub>R</sub> ≤ 20 mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I <sub>R</sub> = 100 μA, f = 20 Hz	1							Ω
Wideband Noise (rms)	I <sub>R</sub> = 100 μA,	120							μV
	10 Hz ≤ f ≤ 10 kHz								
Long Term Stability	I <sub>R</sub> = 100 μA, T = 1000 Hr, T <sub>A</sub> = 25°C ±0.1°C	20							ppm
Average Temperature	Ι <sub>R</sub> = 100 μΑ								
Coefficient (Note 7)	X Suffix		30		30				ppm/°C
	Y Suffix		50		50				ppm/°C
	All Others			150		150		150	ppm/°C (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-2.5 for military specifications.

Note 3: For elevated temperature operation,  $T_{J\,MAX}$  is:

LM185 150°C

LM285 125°C

LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT-23
$\theta_{ia}$ (Junction to Ambient)	180°C/W (0.4 Leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125 Leads)			
$\theta_{jc}$ (Junction to Case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25^{\circ}C$ .

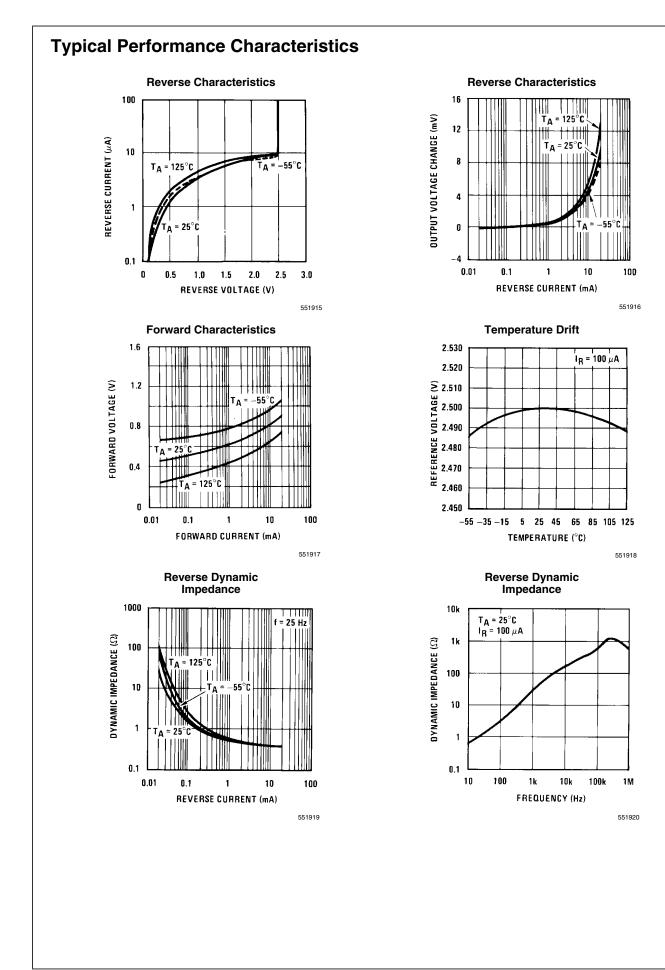
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

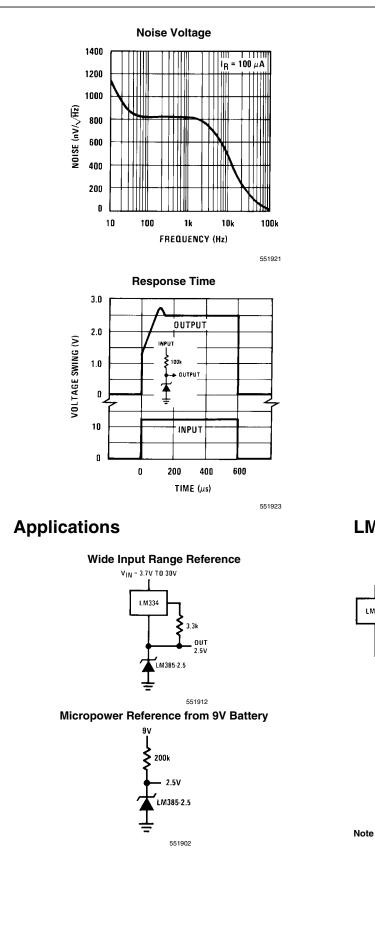
**Note 7:** The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating  $T_{MAX}$  and  $T_{MIN}$ , divided by  $T_{MAX}-T_{MIN}$ . The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

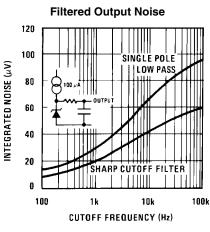
Note 8: A military RETS electrical specification available on request.

Note 9: The human body model is a 100 pF capacitor discharged through a 1.5  $k\Omega$  resistor into each pin.



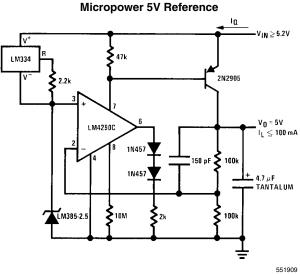




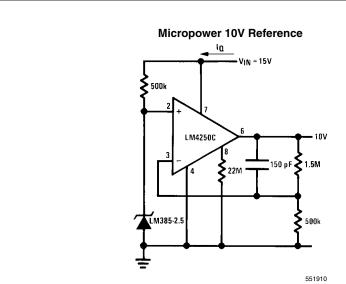


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## LM385-2.5 Applications

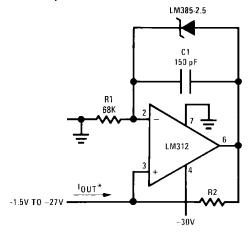


**Note 10:** I<sub>Q</sub> ≃ 40 μA

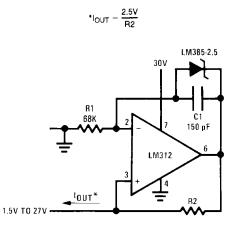


Note 11:  $I_Q \approx 30 \ \mu A$  standby current





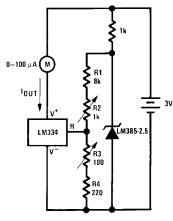
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#### METER THERMOMETERS

#### 0°C–100°C Thermomemter

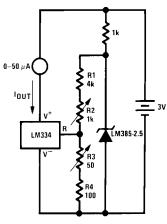




#### Calibration

1. Short LM385-2.5, adjust R3 for  $I_{OUT}$ =temp at 1µA/°K Remove short, adjust R2 for correct reading in centigrade



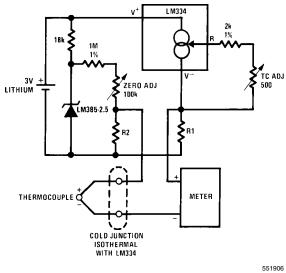


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#### Calibration

1. Short LM385-2.5, adjust R3 for  $I_{OUT}$ =temp at 1.8  $\mu$ A/°K Remove short, adjust R2 for correct reading in °F

#### Micropower Thermocouple Cold Junction Compensator

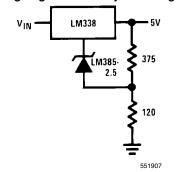


#### **Adjustment Procedure**

- 1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

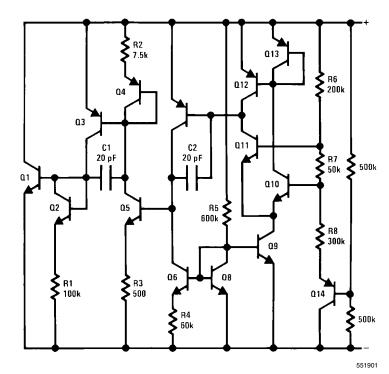
Thermocouple Type	Seebeck Co- efficient ( <sub>u</sub> V/°C)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
Т	42.8	432	1k	12.77	11.78
К	40.8	412	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

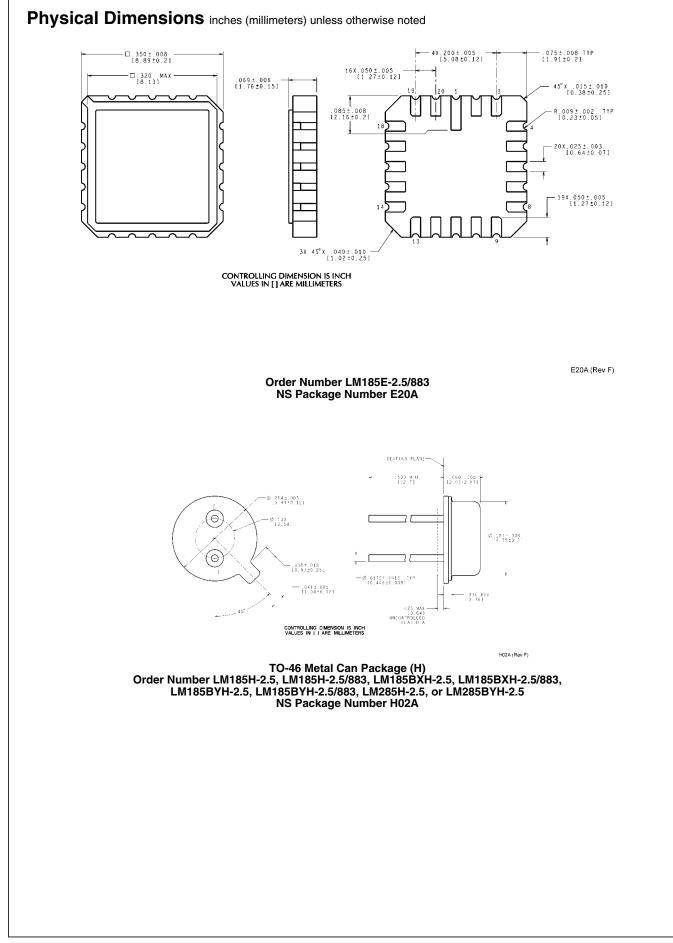
Typical supply current 50  $\mu\text{A}$ 



#### Improving Regulation of Adjstable Regulators

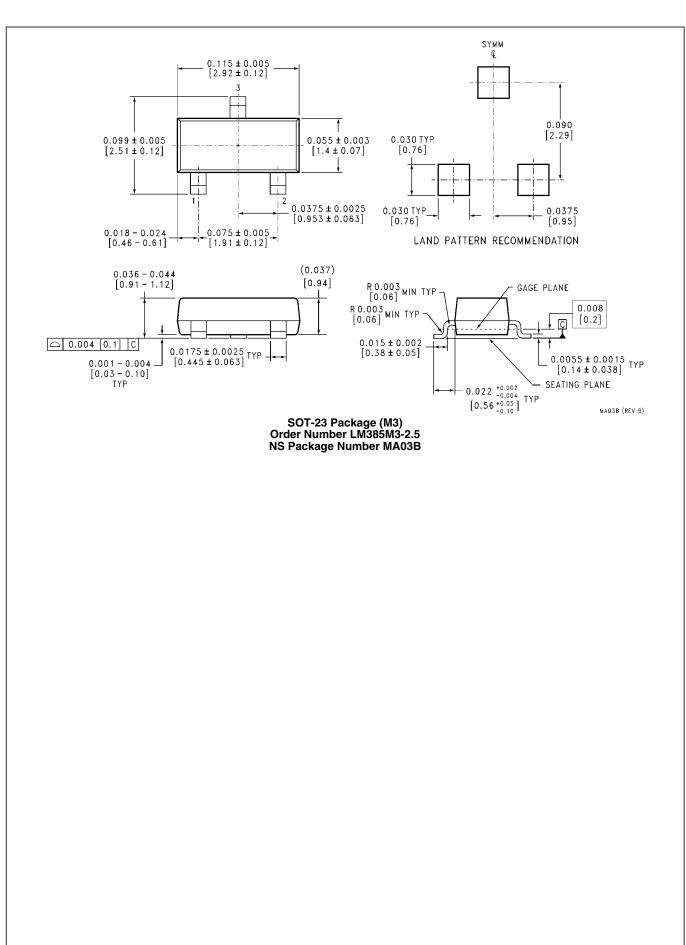
# Schematic Diagram



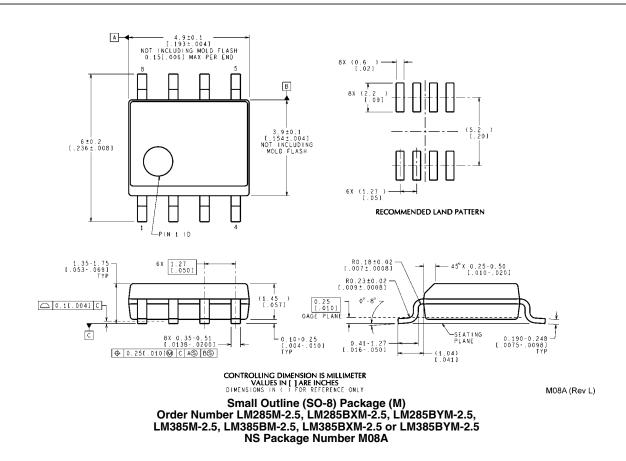


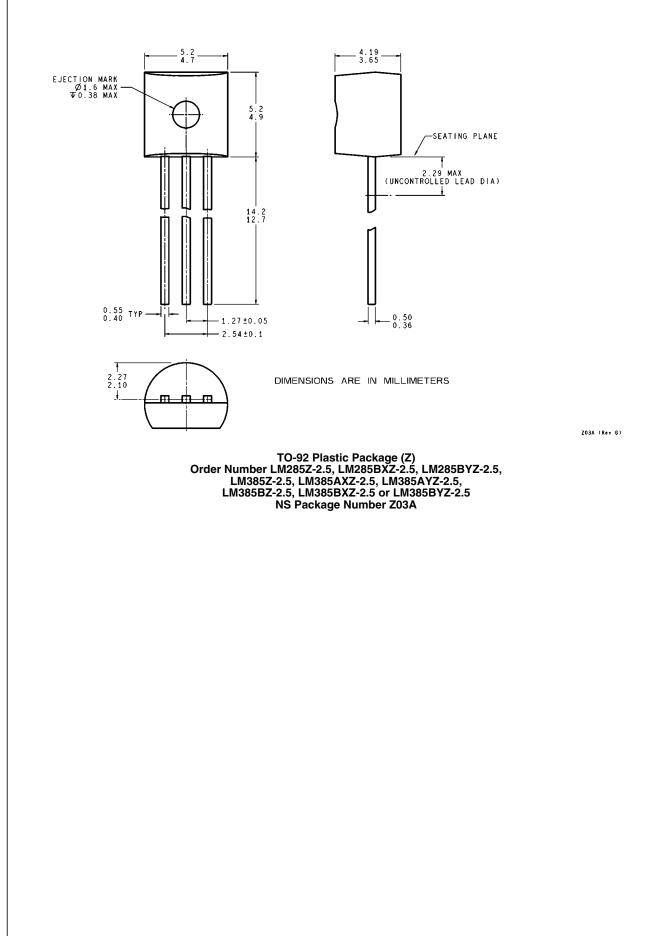
LM185-2.5/LM285-2.5/LM385-2.5

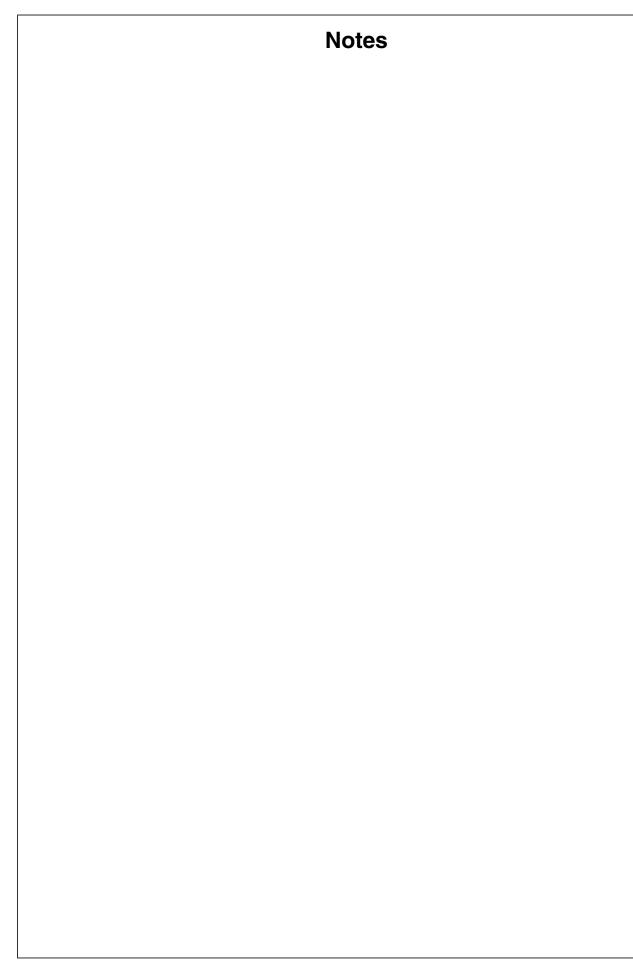












LM185-2.5/LM285-2.5/LM385-2.5

# **Notes**

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Amplifiers	ers www.national.com/amplifiers		www.national.com/webench		
Audio	www.national.com/audio	Analog University	www.national.com/AU		
Clock Conditioners	www.national.com/timing	App Notes	www.national.com/appnotes		
Data Converters	www.national.com/adc	Distributors	www.national.com/contacts		
Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green		
Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging		
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality		
LVDS	www.national.com/lvds	Reference Designs	www.national.com/refdesigns		
Power Management	www.national.com/power	Feedback	www.national.com/feedback		
Switching Regulators	www.national.com/switchers				
LDOs	www.national.com/ldo				
LED Lighting	www.national.com/led				
PowerWise	www.national.com/powerwise				
Serial Digital Interface (SDI)	www.national.com/sdi				
Temperature Sensors	www.national.com/tempsensors				
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